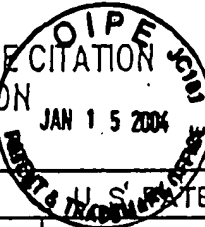


Form PTO-1449

# INFORMATION DISCLOSURE CITATION IN AN APPLICATION

(Use several sheets if necessary)



Document Number (Sequence)

TSMC-01-280B

Application Number

10/686,794

Applicant

Chia-Ta Hsieh

Filing Date

10/16/03

Group Art Unit

## U.S. PATENT DOCUMENTS

EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	ALSO DATE IF APPROPRIATE
SWW	5712179	1/27/98	Yuan	438 <del>437</del>	588 <del>43</del>	10/31/95
SWW	6028336	2/22/00	Yuan	257	315	8/7/97
SWW	5677872	10/14/97	Samachisa et al.	365	185.14	7/8/96
SWW	5278439	1/11/94	Ma et al.	257	319	8/29/91
SWW	6222762	4/24/01	Guterman et al.	365	185.03	8/7/97
SWW	6151248	11/21/00	Harari et al.	365	185.14	6/30/99

## FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

SWW	Y. Ma et al., "A Dual-bit Split-Gate EEPROM (DSG) Cell in Contactless Array for Single-V <sub>cc</sub> High Density Flash Memories," IEDM 94-57, 1994 IEEE, pp. 3.5.1 to 3.5.4.

EXAMINER

DATE CONSIDERED

10-26-2004

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant